

**8-CHANNEL MULTIPLEXER**

The TC74ACT151 is an advanced high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

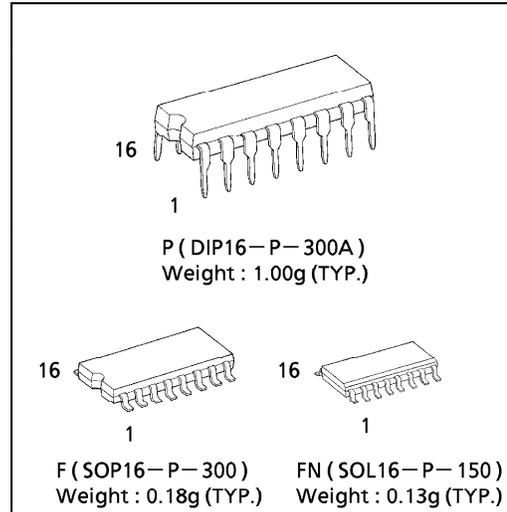
One of eight data input signals (D0 - D7) is selected by decoding of the three-bit address input (A, B, C). The selected data appears on two outputs: non-inverting (Y) and inverting (W).

The STROBE input provides two output conditions; a low level on the STROBE input transfers the selected data to the outputs. A high level on the STROBE input sets the Y output low and the W output high without regard to the data or select input conditions.

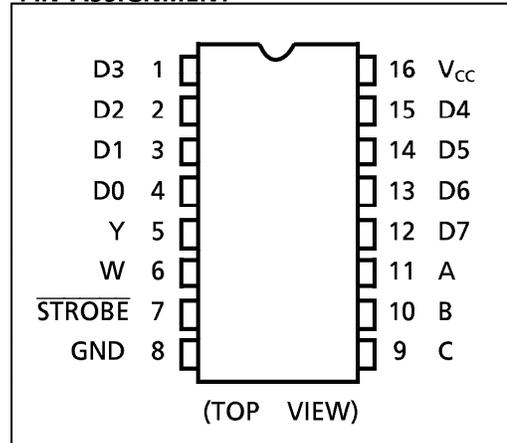
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**FEATURES:**

- High Speed.....  $t_{pd} = 7.1\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation.....  $I_{CC} = 8\mu\text{A}(\text{Max.})$  at  $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs ...  $V_{IL} = 0.8\text{V}(\text{Max.})$   
 $V_{IH} = 2.0\text{V}(\text{Min.})$
- Symmetrical Output Impedance...  $|I_{OH}| = I_{OL} = 24\text{mA}(\text{Min.})$   
Capability of driving  $50\Omega$  transmission lines.
- Balanced Propagation Delays.....  $t_{pLH} \approx t_{pHL}$
- Pin and Function Compatible with 74F151



**PIN ASSIGNMENT**

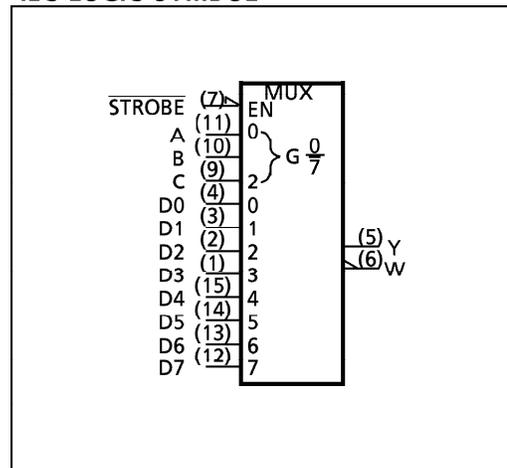


**TRUTH TABLE**

INPUTS				OUTPUT	
SELECT			STROBE	Y	W
C	B	A			
X	X	X	H	L	H
L	L	L	L	D0	$\overline{D0}$
L	L	H	L	D1	$\overline{D1}$
L	H	L	L	D2	$\overline{D2}$
L	H	H	L	D3	$\overline{D3}$
H	L	L	L	D4	$\overline{D4}$
H	L	H	L	D5	$\overline{D5}$
H	H	L	L	D6	$\overline{D6}$
H	H	H	L	D7	$\overline{D7}$

X : Don't Care

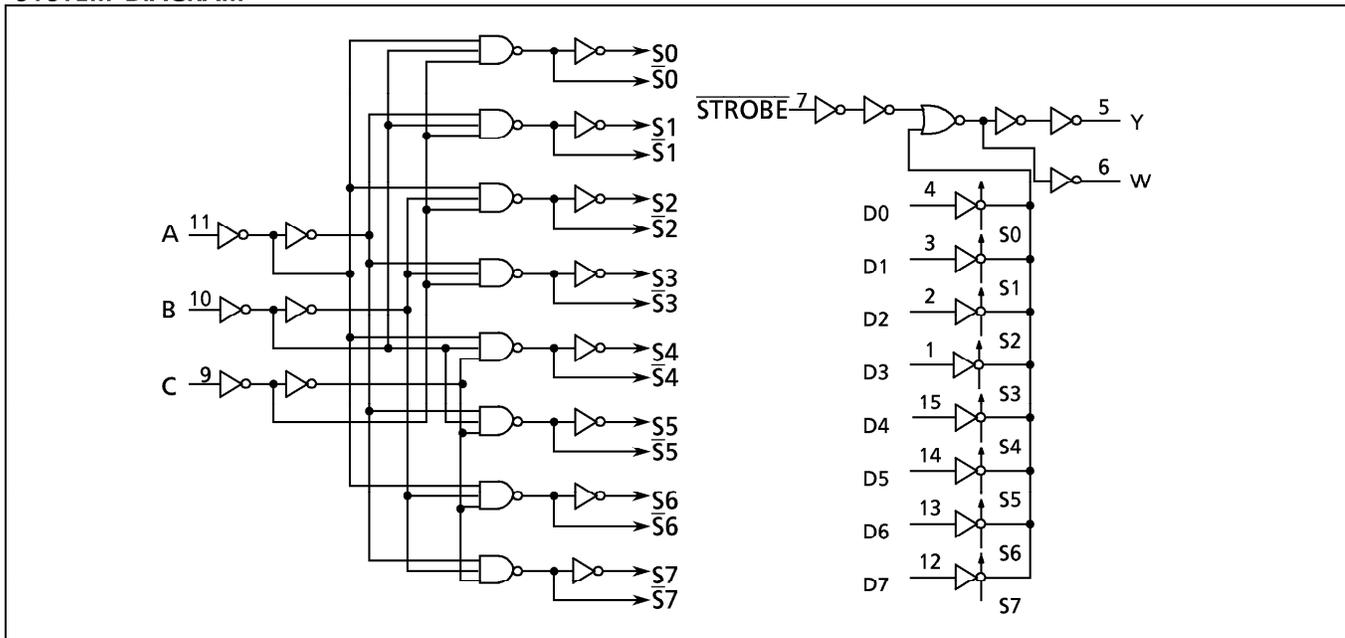
**IEC LOGIC SYMBOL**



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**SYSTEM DIAGRAM**



**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 50$	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 100$	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	$^{\circ}C$

\*500mW in the range of  $T_a = -40^{\circ}C \sim 65^{\circ}C$ . From  $T_a = 65^{\circ}C$  to  $85^{\circ}C$  a derating factor of  $-10mW/^{\circ}C$  should be applied up to 300mW.

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	4.5~5.5	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	$^{\circ}C$
Input Rise and Fall Time	$dt/dV$	0~10	ns/V

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION		V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V <sub>IH</sub>			4.5 ┆ 5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V <sub>IL</sub>			4.5 ┆ 5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50μA	4.5	4.4	4.5	—	4.4	—	V
			I <sub>OH</sub> = -24mA	4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = -75mA *	5.5	—	—	—	3.85	—	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I <sub>OL</sub> = 24mA	4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75mA *	5.5	—	—	—	—	1.65	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	8.0	—	80.0	
		I <sub>C</sub>	PER INPUT : V <sub>IN</sub> = 3.4V OTHER INPUT : V <sub>CC</sub> or GND		5.5	—	—	1.35	—	1.5

\* : This spec indicates the capability of driving 50Ω transmission lines.  
One output should be tested at a time for a 10ms maximum duration.

**AC ELECTRICAL CHARACTERISTICS ( C<sub>L</sub> = 50pF , R<sub>L</sub> = 500Ω , Input t<sub>r</sub> = t<sub>f</sub> = 3ns )**

PARAMETER	SYMBOL	TEST CONDITION		V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (D-Y, W)	t <sub>pLH</sub> t <sub>pHL</sub>			5.0 ± 0.5	—	7.5	11.8	1.0	13.5	ns
				5.0 ± 0.5	—	9.5	15.8	1.0	18.0	
Propagation Delay Time (ST-Y, W)	t <sub>pLH</sub> t <sub>pHL</sub>			5.0 ± 0.5	—	6.3	10.1	1.0	11.5	
Input Capacitance	C <sub>IN</sub>				—	5	10	—	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (1)				—	66	—	—	—	

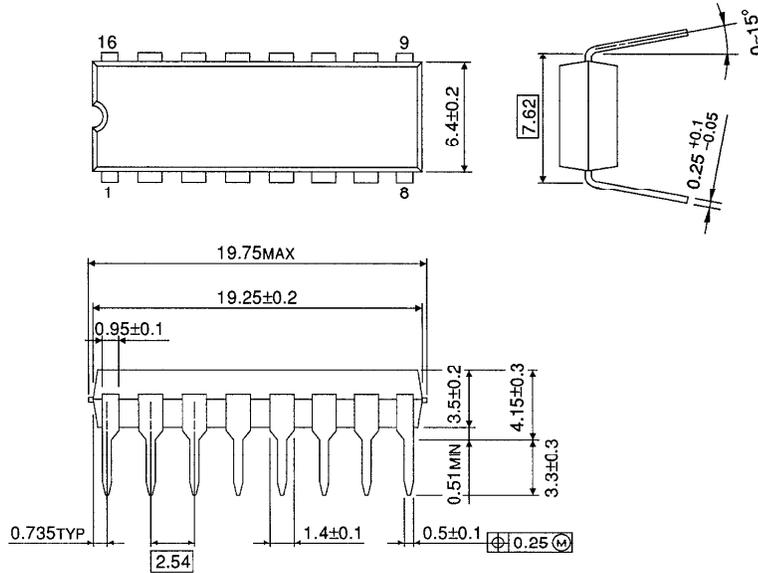
Note(1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

**DIP 16PIN OUTLINE DRAWING (DIP16-P-300A)**

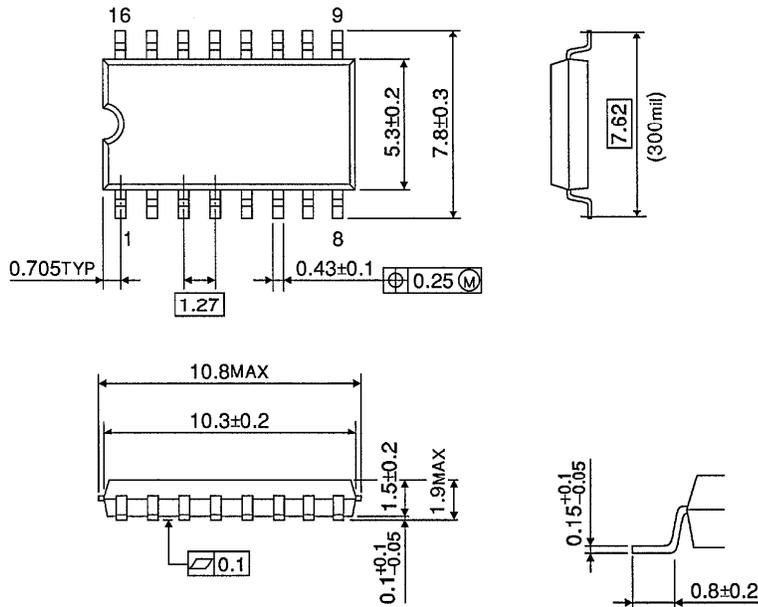
Unit in mm



Weight : 1.00g (TYP.)

**SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300)**

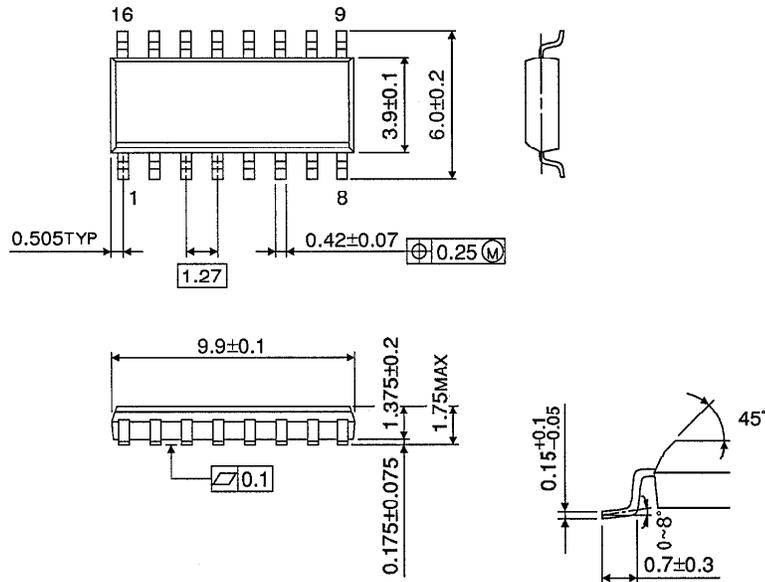
Unit in mm



Weight : 0.18g (TYP.)

**SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150)**

Unit in mm



Weight : 0.13g (TYP.)